

Electronically connected graphene nanoribbons foresee high-speed electronics

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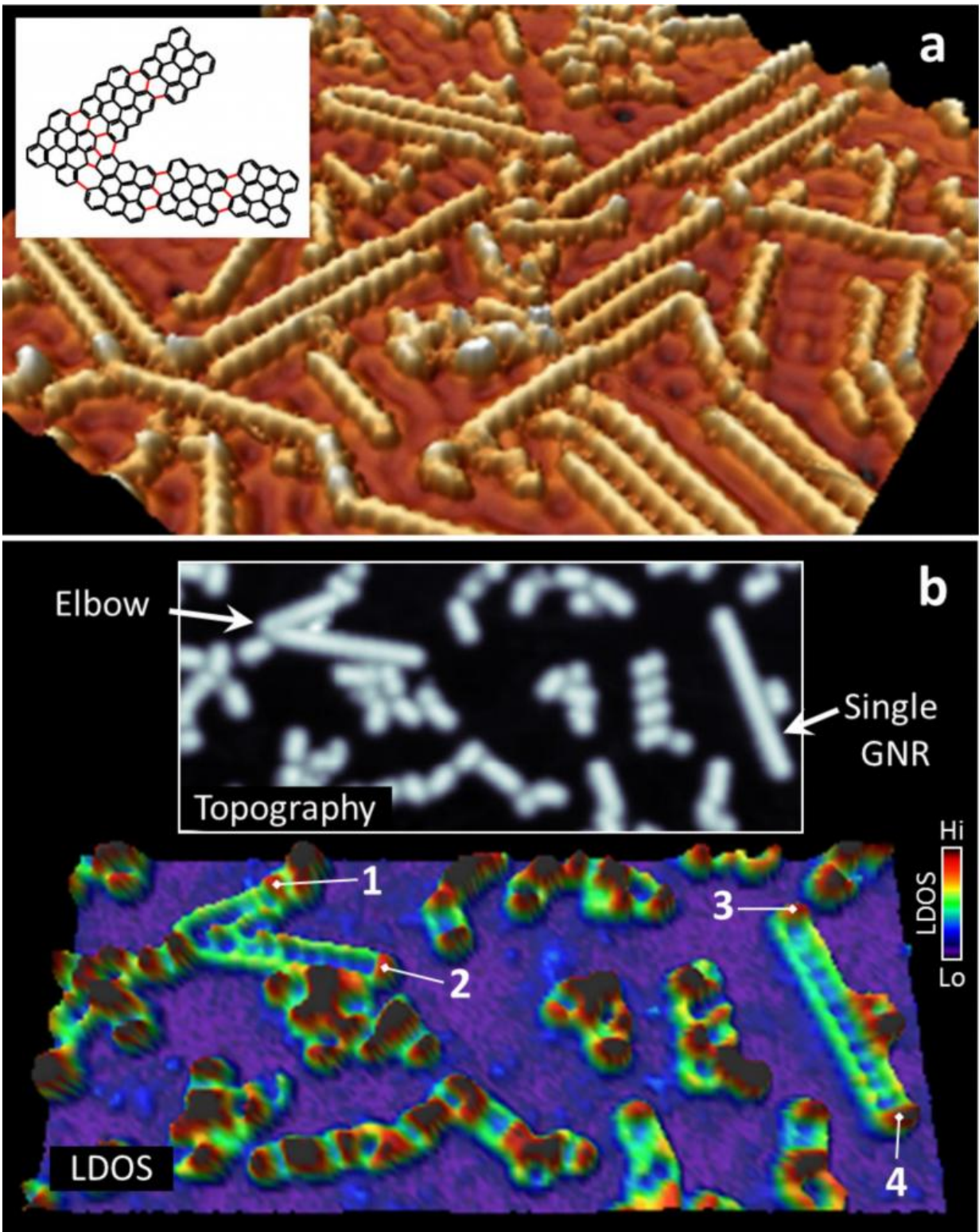


Figure 1 shows interconnected graphene nanoribbons (GNRs). The interconnection points are observed as elbow structures. The inset of (a) shows

the chemical structure of an elbow interconnection point of two chiral-edge GNRs. The top panel of (b) shows the scanning tunneling microscopy topograph, highlighting a single GNR and a pair of connected GNRs (elbow). The bottom panel of (b) shows the local density of states (LDOS) of these two structures share the same electronic architecture, including the elbow interconnection point. This indicates that electronic properties, such as electron and thermal conductivities, should be comparable between termini 1-2 and termini 3-4. Credit: Patrick Han

An international research team at Tohoku University's Advanced Institute of Materials Research (AIMR) succeeded in chemically interconnecting chiral-edge graphene nanoribbons (GNRs) with zigzag-edge features by molecular assembly, and demonstrated electronic connection between GNRs. The GNRs were interconnected exclusively end to end, forming elbow structures, identified as interconnection points (Fig. 1a).

This configuration enabled researchers to demonstrate that the electronic architecture at the interconnection points between two GNRs (Fig. 1b) is the same as that along single GNRs; evidence that GNR electronic properties, such as electron and thermal conductivities, are directly extended through the elbow structures upon chemical GNR interconnection.

This work shows that future development of high-performance, low-power-consumption electronics based on GNRs is possible.

Graphene has long been expected to revolutionize electronics, provided that it can be cut into atomically precise shapes that are connected to desired electrodes. However, while current bottom-up fabrication methods can control graphene's electronic properties, such as high electron mobility, tailored band gaps and s pin-aligned zigzag edges, the

connection aspect of graphene structures has never been directly explored. For example, whether electrons traveling across the interconnection points of two GNRs would encounter higher electric resistance remains an open question. As the answers to this type of questions are crucial towards the realization of future high-speed, low-power-consumption electronics, we use molecular assembly to address this issue here.

"Current molecular assemblies either produce straight GNRs (i.e., without identifiable interconnection points), or randomly interconnected GNRs," says Dr. Patrick Han, the project leader. "These growth modes have too many intrinsic unknowns for determining whether electrons travel across graphene interconnection points smoothly. The key is to design a molecular assembly that produces GNRs that are systematically interconnected with clearly distinguishable interconnection points."

To reach this goal, the AIMR team used a Cu substrate, whose reactivity confines the GNR growth to six directions, and used scanning tunneling microscopy (STM) to visualize the GNR electronic structures. By controlling the precursor molecular coverage, this molecular assembly connects GNRs from different growth directions systematically end to end, producing elbow structures—identified as interconnection points (Fig. 1a). Using STM, the AIMR team revealed that the delocalization of the interconnected GNR π^* -states extends the same way both across a single straight GNR, and across the interconnection point of two GNRs (periodic features in Fig. 1b, bottom panel). This result indicates that GNR [electronic properties](#), such as electron and thermal conductivities, should be the same at the termini of single GNRs and that of two connected GNRs.

"The major finding of this work is that interconnected GNRs do not show electronic disruption (e.g., electron localization that increases resistance at the interconnection points)," says Han. "The electronically

smooth interconnection demonstrates that GNR properties (including tailored band gaps, or even spin-aligned zigzag edges) can be connected to other graphene structures. These results show that finding a way to connect defect-free GNRs to desired electrodes may be the key strategy toward achieving high-performance, low-power-consumption electronics."

More information: Patrick Han et al. Self-Assembly Strategy for Fabricating Connected Graphene Nanoribbons, *ACS Nano* (2015). [DOI: 10.1021/acsnano.5b04879](https://doi.org/10.1021/acsnano.5b04879)

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